TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SZ05F,TC7SZ05FU

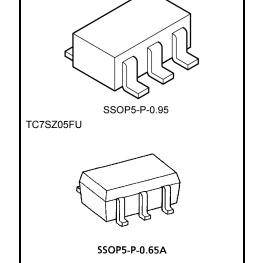
Inverter (Open Drain)

#### **Features**

- High output drive: 24 mA (min) @VCC = 3 V
- Super high speed operation:

$$t_{pz} = 1.9 \text{ ns(typ.)} @V_{CC} = 5 \text{ V}, 50 \text{ pF}$$

- Operation voltage range:  $V_{CC (opr)} = 1.80 \sim 5.5 \text{ V}$
- 5.5V tolerant input.
- · Power down protection is provided on output.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

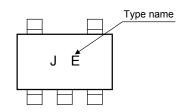


#### Weight

TC7SZ05F

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A : 0.006 g (typ.)

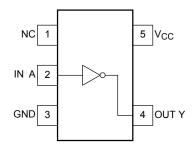




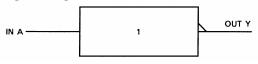
#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	-0.5~6	V	
DC input voltage	V <sub>IN</sub>	-0.5~6	V	
DC output voltage	V <sub>OUT</sub>	-0.5~6	V	
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	lok	-20	mA	
DC output current	lout	50	mA	
DC V <sub>CC</sub> /ground current	Icc	±50	mA	
Power dissipation	PD	200	mW	
Storage temperature	T <sub>stg</sub> –65~150		°C	
Lead temperature (10s)	TL	260	°C	

### Pin Assignment (top view)



# **Logic Diagram**



#### **Truth Table**

Α	Υ
L	*Z
Н	L

\*: High impedance

# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	1.8~5.5	V	
Supply voltage	v.C.C.	1.5~5.5 (Note 1)	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V	
		0~V <sub>CC</sub> (Note 3)	v	
Operating temperature	T <sub>opr</sub>	− <b>40~8</b> 5	°C	
	dt/dv	$0\sim20~(V_{CC}=1.8~V,~2.5~V\pm0.2~V)$		
Input rise and fall time		$0\sim10~(V_{CC}=3.3~V\pm0.3~V)$	ns/V	
		$0\sim5 \ (V_{CC} = 5.5 \ V \pm 0.5 \ V)$		

Note 1: Data retention only

Note 2: OFF state
Note 3: Low state

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics 5		Cumple al	Toot	Condition		Ta = 25°C			Ta = -40~85°C		Unit
Characteris	SIICS	Symbol	ool Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
Input voltage  Low level	High level	V <sub>IH</sub>			1.8	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75		
	VIH			2.3~5.5	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	_	V	
	I ow level	.,			1.8		ı	V <sub>CC</sub> × 0.25	ı	V <sub>CC</sub> × 0.25	V
	V <sub>IL</sub>	_		2.3~5.5			V <sub>CC</sub> × 0.3		V <sub>CC</sub> × 0.3		
High level 0utput le	akage	I <sub>LKG</sub>	$V_{IN} = V_{IL}$		1.8~5.5	_	_	±5	_	±10	μΑ
				1.8	_	0	0.1	_	0.1		
				Ι <sub>ΟL</sub> = 100 μΑ	2.3	_	0	0.1	_	0.1	V
		V <sub>OL</sub> V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>		3.0	_	0	0.1	_	0.1	
	V				4.5	_	0	0.1		0.1	
Output voltage	VOL			I <sub>OL</sub> = 8 mA	2.3	_	0.1	0.3	_	0.3	
				I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	_	0.4	
				I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55	_	0.55	
				I <sub>OL</sub> = 32 mA	4.5	_	0.22	0.55	_	0.55	
Input leakage current $I_{IN}$ $V_{IN} = 5.5 \text{ V or GND}$		0~5.5	_	_	±1	_	±10	μΑ			
Power off leakage	current	I <sub>OFF</sub> V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0.0	_	_	1	_	10	μΑ	
Quiescent supply current $I_{CC}$ $V_{IN} = V_{CC}$ or GND		5.5	_	_	2	_	20	μΑ			

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# AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

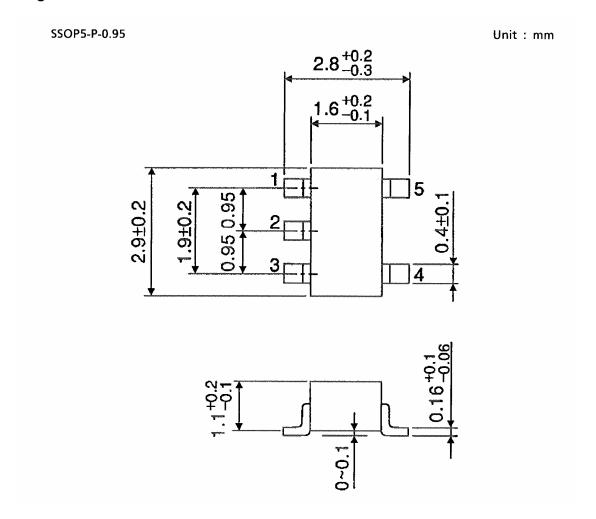
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		- Unit
Characteristics	Syllibol		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	t <sub>pZL</sub>	$\begin{aligned} C_L &= 50 \text{ pF}, \\ R_L &= 500 \ \Omega \end{aligned}$	1.8	1.5	4.6	10.5	1.5	11.0	- ns
			$2.5 \pm 0.2$	0.8	3.0	7.0	0.8	7.5	
			$3.3 \pm 0.3$	0.8	2.4	5.0	0.8	5.2	
			$5.0 \pm 0.5$	0.5	1.9	4.3	0.5	4.5	
	t <sub>pLZ</sub>	$\begin{aligned} C_L &= 50 \text{ pF}, \\ R_L &= 500 \ \Omega \end{aligned}$	1.8	1.5	4.1	10.5	1.5	11.0	- ns
			$2.5 \pm 0.2$	0.8	2.5	7.0	0.8	7.5	
			$3.3 \pm 0.3$	0.8	2.1	5.0	0.8	5.2	
			$5.0 \pm 0.5$	0.5	1.2	4.3	0.5	4.5	
Input capacitance	C <sub>IN</sub>	_	0~5.5		4				pF
Power dissipation capacitance	C	(Note 4)	3.3		3.6			_	- pF
	C <sub>PD</sub>		5.5		6.5		_	_	

Note 4: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

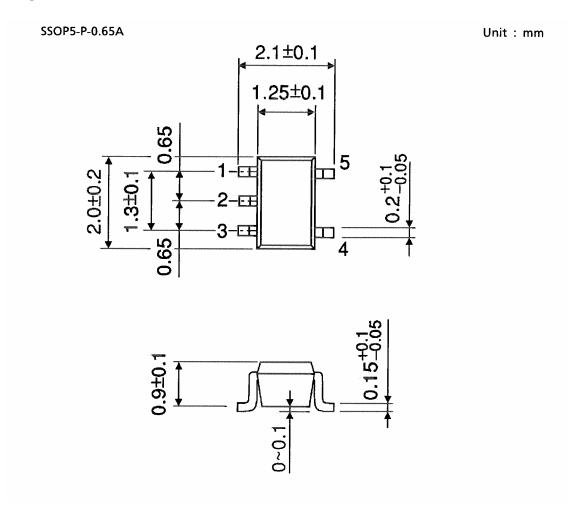
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# **Package Dimensions**



Weight: 0.016 g (typ.)

# **Package Dimensions**



Weight: 0.006 g (typ.)

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